

Isc N-Channel MOSFET Transistor

STB23NM50N

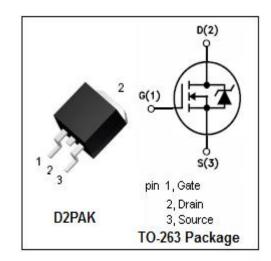
• FEATURES

- · With To-263(D2PAK) package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

Switching applications

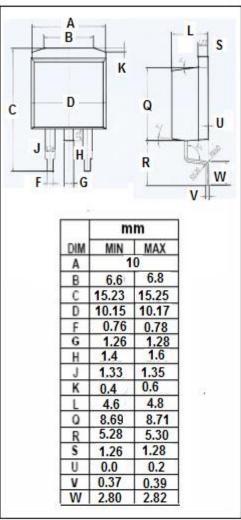


• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	/oltage 500		
V _{GSS}	Gate-Source Voltage	V		
I _D	Drain Current-Continuous@ T_c =25° C T_c =125° C	А		
I _{DM}	Drain Current-Single Pulsed 68		Α	
P _D	Total Dissipation @Tc=25℃	pation @T _C =25℃ 125		
T _{ch}	Max. Operating Junction Temperature	150	$^{\circ}\mathbb{C}$	
T _{stg}	Storage Temperature -55~150		$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1	°C/W
Rth(ch-a)	Channel-to-ambient thermal resistance	30	°C/W





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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	500			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = ±25V; I _D =0.25mA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =8.5A		162	190	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±25V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 500V; V _{GS} = 0V; T _J =25°C T _J =125°C			1 100	μА
V _{SDF}	Diode forward voltage	I _{SD} =17A, V _{GS} = 0 V			1.5	V

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